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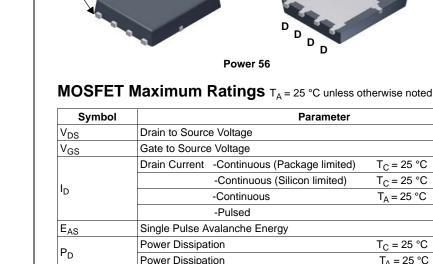


ON Semiconductor®

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FAIRCHILD

FDMS86310

80 V, 50 A, 4.8 mΩ

and high efficiency

■ 100% UIL tested

RoHS Compliant

Pin 1

engineered for soft recovery

Тор

MSL1 robust package design

Features

N-Channel PowerTrench[®] MOSFET

■ Advanced Package and Silicon combination for low r_{DS(on)}

• Max $r_{DS(on)}$ = 4.8 m Ω at V_{GS} = 10 V, I_D = 17 A

• Max $r_{DS(on)} = 6.7 \text{ m}\Omega$ at $V_{GS} = 8 \text{ V}$, $I_D = 14 \text{ A}$

■ Next generation enhanced body diode

T_Δ = 25 °C (Note 1a) (Note 3) T_C = 25 °C 25 00







technology,

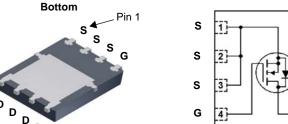


General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency and to minimize switch node ringing of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{\text{DS(on)}}$, fast switching speed and body diode reverse recovery performance.

Applications

Synchronous Rectifier



D D 7 6 D D 5

Ratings 80 ±20 $T_C = 25 \ ^{\circ}C$ 50 $T_C = 25 \ ^{\circ}C$ 105 17 100 183 96 2 5

-	Power Dissipation	$I_{A} = 25 {}^{\circ}C$	(Note 1a)	2.5			
T _J , T _{STG}	Operating and Storage Junction Temperature Ran	nge		-55 to +150			
Thermal Characteristics							

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	1.3	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient (Note	1a) 50	C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86310	FDMS86310	Power 56	13 "	12 mm	3000 units

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Units

V

V

А

mJ

W

°С

October 2014

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	80			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		45		mV/°C
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 64 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	2.4	3.3	4.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_{.1}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-11		mV/°C
5	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 17 A		3.8	4.8	
r _{DS(on)}		$V_{GS} = 8 \text{ V}, I_{D} = 14 \text{ A}$		4.5	6.7	mΩ
		V _{GS} = 10 V, I _D = 17 A, T _J = 125 °C		5.7	7.2	
9 _{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 17 \text{ A}$		49		S
C _{iss} C _{oss}	Input Capacitance Output Capacitance	V _{DS} = 40 V, V _{GS} = 0 V, f = 1 MHz		4730 693	6290 925	pF pF
-						
C _{rss} R _g	Reverse Transfer Capacitance Gate Resistance			19 1.3	45	pF Ω
	g Characteristics			28	45	
t _{d(on)}	Rise Time			20	45 37	ns
t _r	Turn-Off Delay Time	$V_{DD} = 40 \text{ V}, \text{ I}_{D} = 17 \text{ A},$ $V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		35	56	ns ns
t _f	Fall Time	VGS = 10 V, NGEN = 0 11		9	18	ns
Q _q	Total Gate Charge	V _{GS} = 0 V to 10 V		66	95	nC
Q _q	Total Gate Charge	$\frac{V_{GS} = 0 \text{ V to } 10 \text{ V}}{V_{GS} = 0 \text{ V to } 8 \text{ V}} \text{ V}_{DD} = 40 \text{ V},$ $I_{D} = 17 \text{ A}$		55	78	nC
Q _{gs}	Gate to Source Charge			24		nC
Q _{gd}	Gate to Drain "Miller" Charge			14		nC
•	urce Diode Characteristics					
		$V_{GS} = 0 V, I_{S} = 2.1 A$ (Note 2)		0.72	1.2	- V
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 17 A$ (Note 2) $V_{GS} = 0 V, I_S = 17 A$ (Note 2)		0.81	1.2	
t _{rr}	Reverse Recovery Time			51	80	ns
Q _{rr}	Reverse Recovery Charge	—I _F = 17 A, di/dt = 100 A/μs		41	65	nC
	in the second se			1		

Q_{rr}

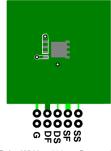
t_{rr}

Notes: 1. R_{0JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.

a) 50 °C/W when mounted on a 1 in² pad of 2 oz copper

 $I_{\rm F} = 17$ A, di/dt = 300 A/µs





Reverse Recovery Time

Reverse Recovery Charge

2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

3. Starting T_J = 25 °C, L = 0.3 mH, I_{AS} = 35 A, V_DD = 72 V, V_{GS} = 10 V.



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b) 125 °C/W when mounted on a minimum pad of 2 oz copper.

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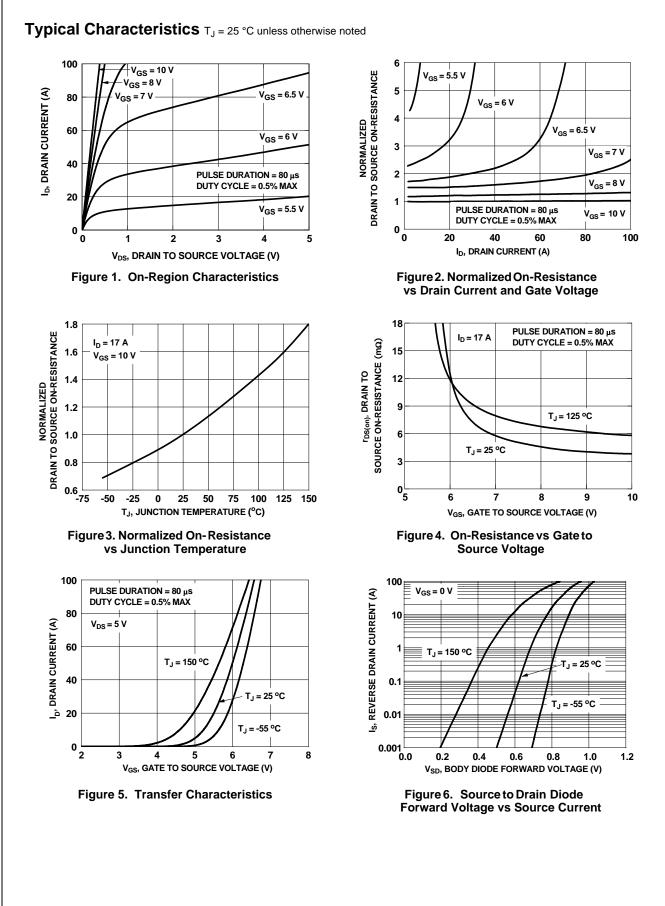
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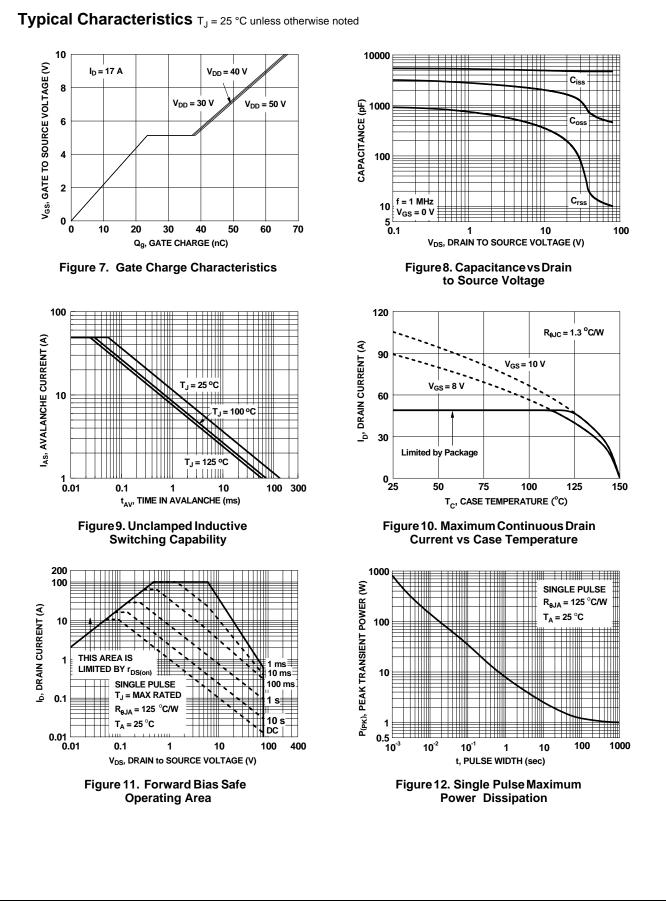
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ns

nC

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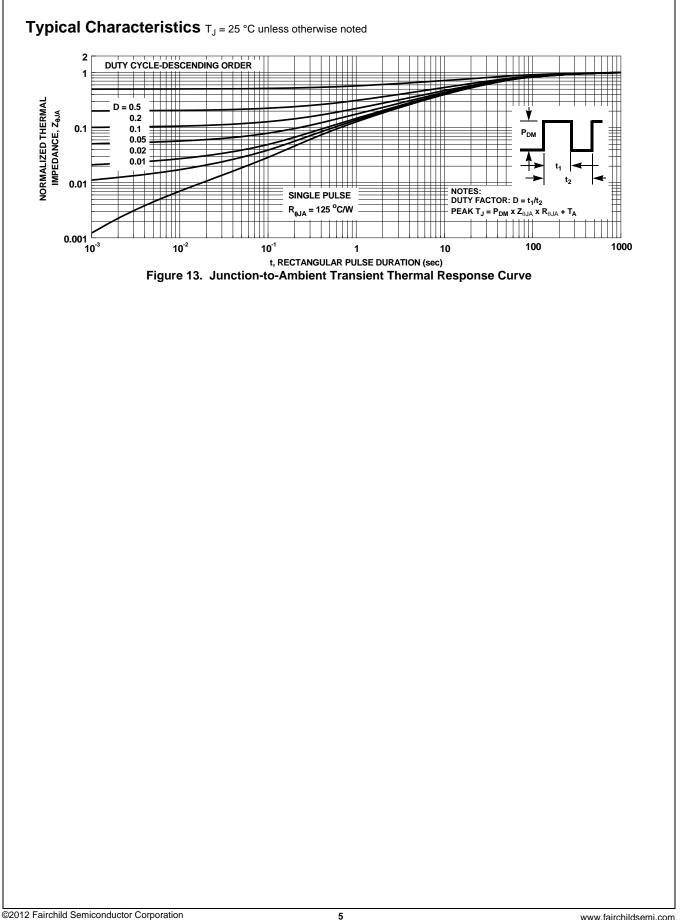




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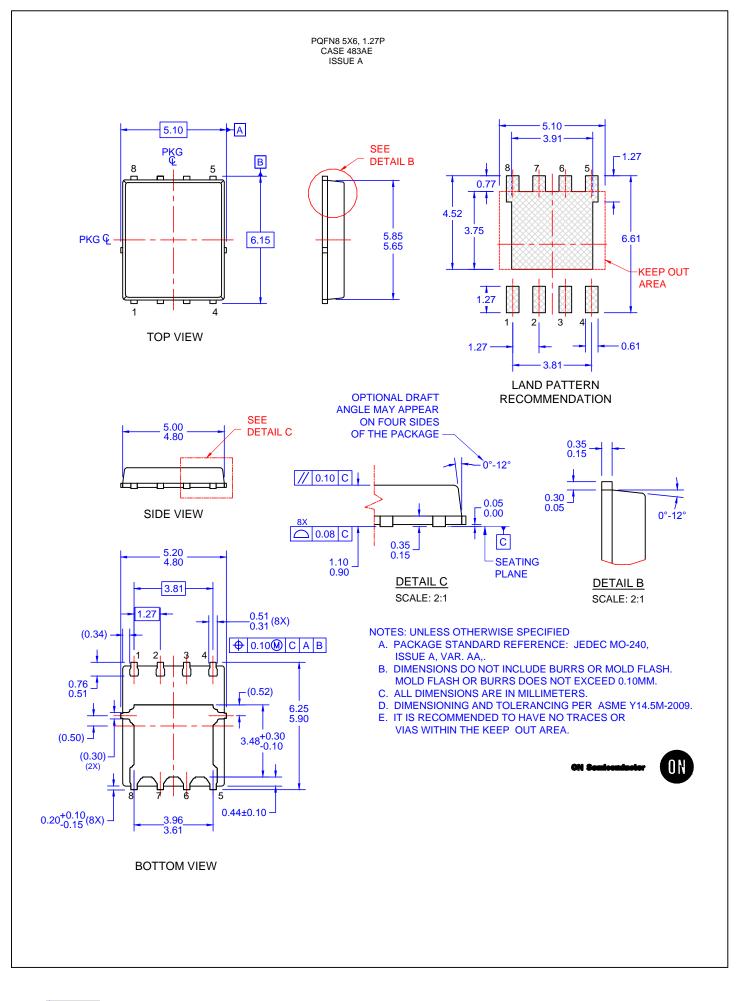
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FDMS86310 N-Channel PowerTrench[®] MOSFET



FDMS86310 Rev. C1

FDMS86310 N-Channel PowerTrench[®] MOSFET



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